General Description

The MAX4533 guad, single-pole/double-throw (SPDT), fault-protected analog switch is pin-compatible with the industry-standard MAX333 and MAX333A. The MAX4533 features fault-protected inputs and Rail-to-Rail® signal handling. The normally open (NO_) and normally closed (NC_) terminals are protected from overvoltage faults up to ±25V with power on and up to ±40V with power off. During a fault condition, NO_ and NC_ become high impedance with only nanoamperes of leakage current flowing to the source. In addition, the output (COM_) clamps to the appropriate polarity supply rail and provides up to ±10mA of load current. This ensures unambiguous rail-to-rail outputs when a fault occurs.

The MAX4533 operates from dual ±4.5V to ±18V power supplies or a single +9V to +36V supply. All digital inputs have +0.8V and +2.4V logic thresholds, ensuring both TTL and CMOS logic compatibility when using ±15V supplies or a +12V supply. On-resistance is 175Ω max and is matched between switches to 10Ω max. The offleakage current is only 0.5nA at $T_A = +25^{\circ}C$ and 10nA at $T_A = +85^{\circ}C.$

	nppnoanono
Redundant/Backup Systems	Portable Instruments
Test Equipment	Data-Acquisition
Communications Systems	Systems
Industrial and Process Control	Avionics Systems

Typical Operating Circuit INPUTS OUTPUTS V1 V1 - V2 V2 OSC IN MIXIM лл MAX4533 V3 - V4 V3 V4

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd. † Patent Pending

FLYING CAPACITOR LEVEL TRANSLATOR (2-CHANNEL)

M/IXI/M

Applications

Features

- ±40V Fault Protection with Power Off ±25V Fault Protection with ±15V Supplies
- All Switches Off with Power Off

Rail-to-Rail Signal Handling

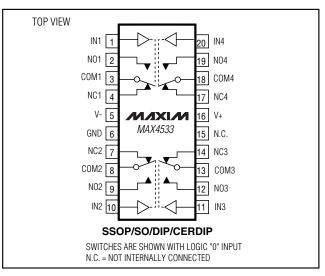
- No Power-Supply Sequencing Required During Power-Up or Power-Down
- Output Clamped to Appropriate Supply Voltage **During Fault Condition—No Transition Glitch**
- 1kΩ (typ) Output Clamp Resistance During Overvoltage
- 175Ω (max) Signal Paths with ±15V Supplies
- 20ns (typ) Fault Response Time
- ♦ ±4.5V to ±18V Dual Supplies +9V to +36V Single Supply
- Pin-Compatible with Industry-Standard MAX333/MAX333A
- TTL/CMOS-Compatible Logic Inputs with ±15V or Single +9V to +15V Supplies

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE					
MAX4533CAP	0°C to +70°C	20 SSOP					
MAX4533CWP	0°C to +70°C	20 Wide SO					
Ordering Informati	Ordering Information continued at and of data about						

Ordering Information continued at end of data sheet.

Pin Configuration/ **Functional Diagram**



Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND

V+	0.3V to +44.0V
V	44.0V to +0.3V
V+ to V	0.3V to +44.0V
COM_, IN_ (Note 1)	(V 0.3V) to (V+ + 0.3V)
NC_, NO_ (Note 2)	(V+ - 40V) to (V- + 40V)
NC_, NO_ to COM	40V to +40V
NC_, NO_ Overvoltage with Switch	Power On
(supplies at ±15V)	30V to +30V
NC_, NO_ Overvoltage with Switch	Power Off40V to +40V
Continuous Current into Any Termin	nal±30mA
Peak Current into Any Terminal	
(pulsed at 1ms,10% duty cycle)	±50mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)
20-Pin SSOP (derate 10.53mW/°C above +70°C)842mW
20-Pin Wide SO (derate 10.00mW/°C above +70°C) 800mW
20-Pin Plastic DIP (derate 11.11mW/°C above +70°C) 889mW
20-Pin CERDIP (derate 11.11mW/°C above +70°C)889mW
Operating Temperature Ranges
MAX4533C0°C to +70°C
MAX4533E40°C to +85°C

MAX4533M__.....55°C to +125°C Storage Temperature Range65°C to +150°C Lead Temperature (soldering, 10s)+300°C

///XI//

Note 1: COM_ and IN_ pins are not fault protected. Signals on COM_ or IN_ exceeding V+ or V- are clamped by internal diodes. Limit forward diode current to maximum current rating.

Note 2: NC_ and NO_ pins are fault protected. Signals on NC_ or NO_ exceeding -25V to +25V may damage the device. These limits apply with power applied to V+ or V-. The limit is ±40V with V+ = V- = 0.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

 $(V + = +15V, V - = -15V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS
ANALOG SWITCH							
Fault-Free Analog Signal Range (Note 2)	V _{NO_} , V _{NC_}	V + = +15V, V - = -15V, V _{NO} _ or V _{NC} _ = ±15V	C, E, M	V-		V+	V
COM to NO or COM to NO			+25°C		125	175	
COM_ to NO_ or COM_ to NC_ On-Resistance	Ron	V_{NO} or V_{NC} = ±10V, ICOM = 1mA	C, E			200	Ω
			М			250	
COM_ to NO_ or COM_ to NC_			+25°C		1	6	
On-Resistance Match Between	ΔR_{ON}	V_{NO} or V_{NC} = ±10V, ICOM = 1mA	C, E			10	Ω
Channels (Note 4)			М			15	
On-Resistance Flatness		V _{COM} = +5V, 0, -5V, I _{COM} = 1mA	+25°C		4		Ω
		$V_{NO_{-}}$ or $V_{NC_{-}} = \pm 14V$, $V_{COM_{-}} = \mp 14V$	+25°C	-0.5	0.02	0.5	nA
NO_ or NC_ Off-Leakage Current (Note 5)			C, E	-10		10	
Current (Note 5)			М	-200		200	
	ICOM_(ON)	$V_{COM} = \pm 14V,$ V_{NO} or $V_{NC} = \pm 14V$ or floating	+25°C	-0.5	0.01	0.5	nA
COM_ On-Leakage Current (Note 5)			C, E	-20		20	
(Note 3)			М	-400		400	
FAULT		1					
Fault-Protected Analog Signal		Applies with power on	+25°C	-25		+25	v
Range (Note 2)	V _{NO} , V _{NC}	Applies with power off	+25°C	-40		+40	V
		24	+25°C	-10		10	
COM_ Output Leakage Current, Supplies On		V_{NO} or V_{NC} = ±25V, no connection to "ON" channel	C, E	-200		200	- nA
			М	-10		10	μA
			+25°C	-20		20	n۸
NO_ or NC_ Off Input Leakage Current, Supplies On	I _{NO_} , I _{NC} _	$V_{NO_}$ or $V_{NC_} = \pm 25V$, $V_{COM_} = \mp 10V$	C, E	-200		200	- nA
			М	-10		10	μA

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = +15V, V- = -15V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
			+25°C	-20	0.1	20		
NO_ or NC_ Input Leakage Current, Supplies Off	I _{NO_} , I _{NC} _	V_{NO} or V_{NC} = ±40V, V+ = 0, V- = 0	C, E	-200		200	nA	
Current, Supplies Off		V+ = 0, V- = 0	М	-10		10	μA	
COM_ On-Clamp Output	loov	V_{NO} or V_{NC} = +25V	+25°C	8	11	13	m۸	
Current, Supplies On	ICOM_	V_{NO} or V_{NC} = -25V	+25°C	-12	-10	-7	mA	
COM_ On-Clamp Output Resistance, Supplies On	RCOM_	V_{NO} or $V_{NC} = \pm 25V$	+25°C C, E, M		1.0	2.5 3	kΩ	
±Fault Output Clamp Turn-On Delay Time (Note 6)		$R_L = 10k\Omega$, V _{NO} _ or V _{NC} _ = ±25V	+25°C		20		ns	
±Fault Recovery Time (Note 6)		$ \begin{array}{l} R_{L} = 10 k\Omega, \\ V_{NO} \text{ or } V_{NC} = \pm 25 V \end{array} $	+25°C		2.5		μs	
LOGIC INPUT								
IN_ Input Logic Threshold High	V _{IN_H}		C, E, M	2.4			V	
IN_ Input Logic Threshold Low	V _{IN_L}		C, E, M			0.8	V	
IN_ Input Current Logic High or	har in har i	$V_{IN} = +0.8V \text{ or } +2.4V$	+25°C	-1	0.03	1		
Low	IIN_H, IIN_L	$v_{IN} = +0.0v \text{ OI } +2.4v$	C, E, M	-5		5	- μΑ	
SWITCH DYNAMIC CHARACTE	RISTICS							
		101/	+25°C		100	250		
Turn-On Time	ton	$V_{COM_} = \pm 10V,$ $R_L = 2k\Omega;$ Figure 2	C, E			400	ns	
			М			600		
	toff	$V_{NO_{-}} = \pm 10V,$ $R_{L} = 2k\Omega$; Figure 2	+25°C		60	150	ns	
Turn-Off Time			C, E			300		
			M			450		
Break-Before-Make Time Delay	t _{BBM}	$V_{COM} = \pm 10V,$ $R_{L} = 1k\Omega$; Figure 3	+25°C	10	50		ns	
Charge Injection (Note 6)	Q	C _L = 100pF, V _{COM} _ = 0; Figure 4	+25°C		1.5		рС	
NO_ or NC_ Off-Capacitance	C _{N_(OFF)}	f = 1MHz; Figure 5	+25°C		5		pF	
COM_ On-Capacitance	CCOM_(ON)	f = 1MHz; Figure 5	+25°C		12		pF	
Off-Isolation (Note 7)	VISO	$\label{eq:RL} \begin{array}{l} R_{L} = 50\Omega, \ C_{L} = 15 pF, \\ V_{N_} = 1V_{RMS}, \ f = 1MHz; \\ Figure \ 6 \end{array}$	+25°C		-62		dB	
Channel-to-Channel Crosstalk (Note 8)	Vct	$\label{eq:RL} \begin{array}{l} R_L = 50\Omega, \ C_L = 15 p F, \\ V_{N_{-}} = 1 V_{RMS}, \ f = 1 M Hz; \\ Figure \ 6 \end{array}$	+25°C		-66		dB	
POWER SUPPLY								
Power-Supply Range	V+, V-			±4.5		±18	V	
V+ Supply Current	1.	All $V_{IN} = 0$ or $+5V$,	+25°C			600		
	I+	$V_{NO_{-}} = V_{NC_{-}} = 0$	C, E, M			1000	- μΑ	
V. Supply Current	I	All $V_{IN} = 0$ or $+5V$,	+25°C			400		
V- Supply Current	-	$V_{NO} = V_{NC} = 0$	C, E, M			600	- μΑ	
	1-	All $V_{IN} = 0$ or $+5V$,	+25°C			300	300	
GND Supply Current	IGND	$V_{NO} = V_{NC} = 0$	C, E, M			450	μA	

MAX4533

ELECTRICAL CHARACTERISTICS—Single Supply

(V+ = +12V, V- = 0, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH			II				1
Fault-Free Analog Signal Range (Note 2)	V _{NO_} , V _{NC_}	$V_{+} = +12V, V_{-} = 0,$ $V_{NO_{-}}$ or $V_{NC_{-}} = +12V$ or 0	C, E, M	0		V+	V
		V+ = +12V,	+25°C		260	390	
COM_ to NO_, COM_ to NC_ On-Resistance	Ron	V_{NO} or V_{NC} = +10V,	C, E			450	Ω
		I _{COM} = 1mA	М			525	
COMNO_ On-Resistance		V + = +12V,	+25°C		4	10	
Match Between Channels	ΔR_{ON}	V_{NO} or V_{NC} = +10V,	C, E			20	Ω
(Note 4)		I _{COM} = 1mA	М			30	
NO_ or NC_ Off-Leakage	INO (OFF),	V + = +12V,	+25°C	-0.5	0.01	0.5	
Current (Notes 5, 9)	INC_(OFF)	$V_{COM} = +10V, +1V,$	C, E	-10		10	nA
		V_{NO} or V_{NC} = +1V, +10V	M	-200		200	
COM_ On-Leakage Current		$V_{+} = +12V,$ $V_{COM} = +10V,$ $V_{COM} = +10V,$	+25°C	-0.5	0.01	0.5	-
(Notes 5, 9)	ICOM_(ON)		C, E	-20		20	nA
		V_{NO} or V_{NC} = +10V or floating	М	-400		400	
AULT	I	Γ					1
Fault-Protected Analog Signal	V _{NO_} , V _{NC_}	Applies with power on	+25°C	-25		+25	v
Range (Note 2)		Applies with power off	+25°C	-40		+40	
COM_ Output Leakage Current,	ICOM_ V		+25°C	-10		10	nA
Supply On (Note 9)			C, E	-200		200	
		no connection to "ON" channel	M	-10		10	μΑ
NO_ or NC_ Off Input Leakage		V_{NO} or V_{NC} = ±25V,	+25°C	-20		20	nA
Current, Supply On (Note 9)	I _{NO_} , I _{NC} _	$V_{COM} = 0,$	C, E	-200		200	
		V+ = +12V	M	-10		10	μA
NO_ or NC_ Input Leakage		V_{NO} or $V_{NC} = \pm 40V$,	+25°C	-20	0.1	20	nA
Current, Supply Off (Note 9)	I _{NO_} , I _{NC} _	V + = 0, V - = 0	C, E	-200		200	
			М	-10		10	μA
COM_ On-Clamp Output Current, Supply On	ICOM_	V_{NO} or V_{NC} = ±25V, V+ = +12V	+25°C	2	3	5	mA
COM_ On-Clamp Output Resistance, Supply On	RCOM_	V_{NO} or V_{NC} = ±25V, V+ = +12V	+25°C		2.4	5	kΩ
OGIC INPUT	1	1	11				1
IN_ Input Logic Threshold High	V _{IN_H}		C, E, M	2.4			V
IN_ Input Logic Threshold Low	V _{IN_L}		C, E, M			0.8	V
			i I				1
IN_ Input Current Logic High or	lin h, lin l	$V_{IN} = +0.8V \text{ or } +2.4V$	+25°C	-1	0.03	1	μA

ELECTRICAL CHARACTERISTICS—Single Supply (continued)

(V+ = +12V, V- = 0, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
SWITCH DYNAMIC CHARACTE	RISTICS		I				1	
Turn-On Time	tou	$V_{COM} = +10V,$	+25°C		200	500	ns	
rum-On nme	ton	$R_L = 2k\Omega$; Figure 2	C, E, M			1000		
Turn-Off Time	torr	$V_{COM_} = +10V,$	+25°C		100	300	ns	
	tOFF	$R_L = 2k\Omega$; Figure 2	C, E, M			900	115	
Break-Before-Make Time Delay	tBBM	$V_{COM_} = +10V,$ $R_L = 1k\Omega;$ Figure 3	+25°C	5	100		ns	
Charge Injection	Q	$C_L = 100 pF,$ $V_{COM_} = 0;$ Figure 4	+25°C		2		рС	
NO_ or NC_ Off-Capacitance	C _{N_(OFF)}	f = 1MHz; Figure 5	+25°C		5		pF	
COM_ On-Capacitance	CCOM_(ON)	f = 1MHz; Figure 5	+25°C		15		pF	
Off-Isolation (Note 7)	VISO	$\label{eq:RL} \begin{array}{l} R_{L} = 50\Omega, \ C_{L} = 15 pF, \\ V_{NO_} = 1V_{RMS}, \ f = 1MHz; \\ Figure \ 6 \end{array}$	+25°C		-62		dB	
Channel-to-Channel Crosstalk (Note 8)	VCT	$\label{eq:RL} \begin{array}{l} R_{L} = 50\Omega, \ C_{L} = 15 pF, \\ V_{NO_} = 1 V_{RMS}, \ f = 1 MHz; \\ Figure \ 6 \end{array}$	+25°C		-65		dB	
POWER SUPPLY		-						
Power-Supply Range	V+		C, E, M	9		36	V	
V. Supply Current	l+	All V_{IN} = 0 or +5V,	+25°C			350		
V+ Supply Current		$V_{NO_{-}} = V_{NC_{-}} = 0$	C, E, M			550	- μΑ	
		All $V_{IN} = 0$ or $+12V$,	+25°C			200		
V- and GND Supply Current		$V_{NO} = V_{NC} = 0$	C, E, M			350	- μΑ	
	IGND	All V_{IN} = 0 or +5V,	+25°C			350		
		$V_{NO_{-}} = V_{NC_{-}} = 0$	C, E, M			550	μΑ	

Note 3: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 4: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 5: Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at $T_A = +25^{\circ}C$.

Note 6: Guaranteed by design.

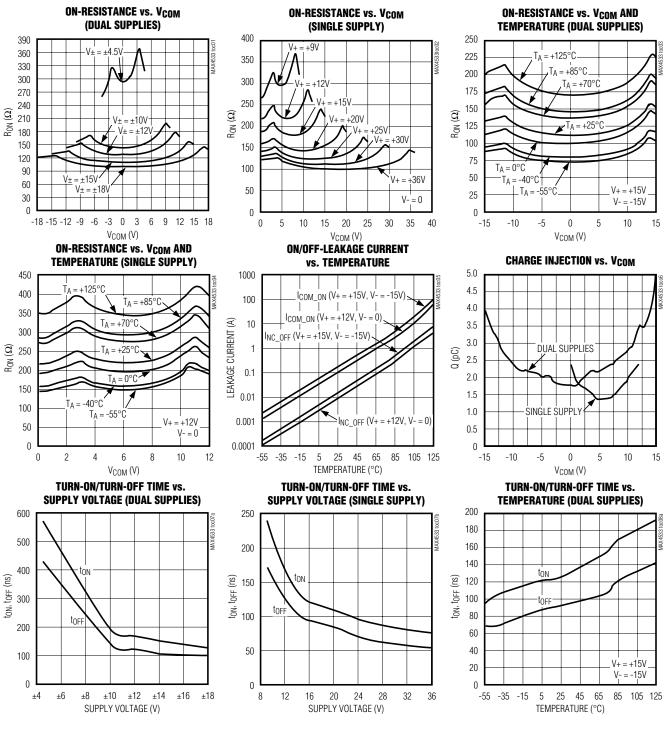
Note 7: Off-isolation = $20\log_{10}(V_{COM_{-}}/V_{NO_{-}})$, $V_{COM_{-}}$ = output, $V_{NO_{-}}$ = input to off switch.

Note 8: Between any two analog inputs.

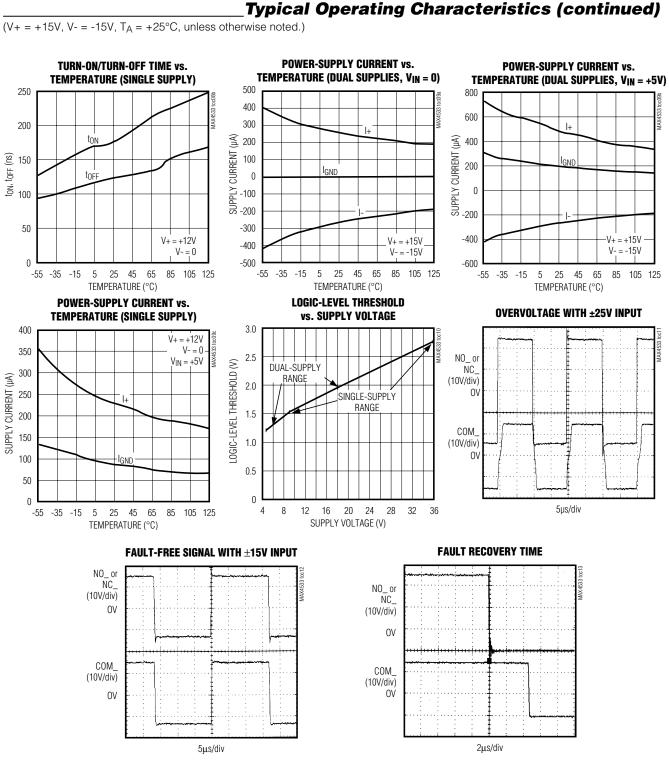
Note 9: Leakage testing for single-supply operation is guaranteed by testing with dual supplies.

 $(V + = +15V, V - = -15V, T_A = +25^{\circ}C, unless otherwise noted.)$

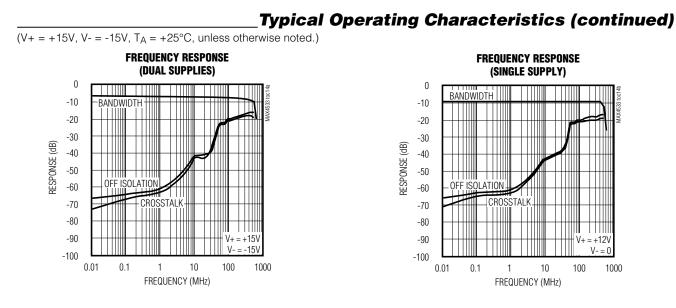
Typical Operating Characteristics



M/IXI/N



/N/IXI/N



Pin Description

PIN	NAME	FUNCTION
1, 10, 11, 20	IN1, IN2, IN3, IN4	Logic Control Digital Inputs
2, 9, 12, 19	NO1, NO2, NO3, NO4	Normally Open Inputs*
3, 8, 13, 18	COM1, COM2, COM3, COM4	Analog Switch Common Outputs*
4, 7, 14, 17	NC1, NC2, NC3, NC4	Normally Closed Inputs*
5	V-	Negative Analog Supply Voltage Input
6	GND	Digital Ground
15	N.C.	No Connection. Not internally connected.
16	V+	Positive Analog and Digital Supply-Voltage Input

*When the voltage on NO_ or NC_ does not exceed V+ or V-, NO_ (or NC_) and COM_ pins are bidirectional.

Detailed Description

The MAX4533 is a fault-protected analog switch with special operation and construction. Traditional fault-protected switches are constructed using three-series CMOS devices. This combination produces good fault protection but fairly high on-resistance when the signals are within about 3V of each supply rail. These series devices are not capable of handling signals up to the power-supply rails.

The MAX4533 differs considerably from traditional faultprotected switches, with three advantages. First, it is constructed with two parallel FETs, allowing very low on-resistance when the switch is on. Second, they allow signals on the NC_ or NO_ pins that are within or slightly beyond the supply rails to be passed through the switch to the COM_ terminal, allowing rail-to-rail signal operation. Third, when a signal on NC_ or NO_ exceeds the supply rails by about 150mV (a fault condition), the voltage on COM_ is limited to the appropriate polarity supply voltage. Operation is identical for both fault polarities. The fault-protection extends to $\pm 25V$ with power on and $\pm 40V$ with power off.

The MAX4533 has a parallel N-channel and P-channel MOSFET switch configuration with input voltage sensors. The simplified internal structure is shown in Figure 1. The parallel N1 and P1 MOSFETs form the switch element. N3 and P3 are sensor elements to sample the input voltage and compare it against the power-supply rails.



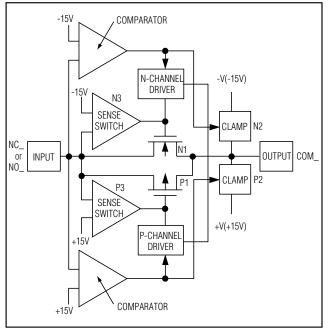


Figure 1. Simplified Internal Structure

During normal operation of a conducting channel, N1 and P1 remain on with a typical 125 Ω on-resistance between NO_ (or NC_) and COM_. If the input voltage exceeds either supply rail by about 150mV, the parallel combination switches (N1, P1) are forced off through the driver and sensing circuitries. At the same time, the output (COM_) is clamped to the appropriate supply rail by the clamp circuitries (N2, P2). Two clamp circuits limit the output voltage to the supply voltages.

For simplicity, Figure 1 shows only one side of the SPDT switch configuration. The complete circuit is composed of two channels with their outputs connected.

Normal Operation

Two comparators continuously compare the voltage on the NO_ (or NC_) pin with V+ and V- supply voltages. When the signal on NO_ (or NC_) is between V+ and V-, the switch behaves normally, with FETs N1 and P1 turning on and off in response to NO_ (or NC_) signals (Figure 1). For any voltage between the supply rails, the switch is bidirectional; therefore, COM_ and NC_ (or NO_) are interchangeable. Only NO_ and NC_ can be exposed to overvoltages beyond the supply range and within the specified breakdown limits of the device.

Fault Condition

The MAX4533 protects devices connected to its output (COM_) through its unique fault-protection circuitry. When the input voltage is raised above either supply rail, the internal sense and comparator circuitries (N3 and N-channel driver or P3 and P-channel driver) disconnect the output (COM_) from the input (Figure 1).

If the switch driven above the supply rail has an on state, the clamp circuitries (N2 or P2) connect the output to the appropriate supply rail. Table 1 summarizes the MAX4533's operation under normal and fault conditions. Row 5 shows a negative fault condition when the supplies are on. It shows that with supplies of $\pm 15V$, if the input voltage is between -15V and -25V, the output (COM_) clamps to the negative supply rail of -15V. With this technique, the SPDT switch is capable of withstanding a worse-case condition of opposite fault polarities at its inputs.

Transient Fault Condition

When a fast rising or falling transient on NO_ (or NC_) exceeds V+ or V-, the output (COM_) follows the input (IN_) to the supply rail by only a few nanoseconds. This delay is due to the switch on-resistance and circuit capacitance to ground. However, when the input transient returns to within the supply rails there is a longer recovery time. For positive faults, the recovery time is typically 2.5 μ s. For negative faults, the recovery time is typically 1.3 μ s. These values depend on the COM_ output resistance and capacitance. The delays are not dependent on the fault amplitude. Higher COM_ output resistance and capacitance increase the recovery times.

Fault Protection, Voltage, and Power Off

The maximum fault voltage on the NO_ or NC_ pins is $\pm 40V$ from ground when the power is off. With $\pm 15V$ supply voltages, the highest voltage on NO_ (or NC_) can be +25V, and the lowest voltage on NO_ (or NC_) can be -25V. Exceeding these limits can damage the chip.

IN_ Logic-Level Thresholds

The logic-level thresholds are TTL/CMOS-compatible when V+ is +15V. Raising V+ increases the threshold slightly; when V+ reaches +25V, the level threshold is 2.8V—higher than the TTL output high-level minimum of 2.4V, but still compatible with CMOS outputs (see the *Typical Operating Characteristics*).

Increasing V- has no effect on the logic-level thresholds, but it does increase the gate-drive voltage to the signal FETs, reducing their on-resistance.

POWER SUPPLIES (V+, V-)	INPUT RANGE	NC_	NO_	OUTPUT
On	Between Rails	On	Off	NC_
On	Between Rails	Off	On	NO_
On	Between V+ and (+40V - V+)	On	Off	V+
On	Between V+ and (+40V - V+)	Off	On	V+
On	Between V- and (-40V - V-)	On	Off	V-
On	Between V- and (-40V - V-)	Off	On	V-
Off	Between Rails	Off	Off	Follows the load terminal voltage.

Table 1. Switch States in Normal and Fault Conditions

Failure Modes

The MAX4533 is not a lightning arrester or surge protector. Exceeding the fault-protection voltage limits on NO_ or NC_, even for very short periods, can cause the device to fail.

Applications Information

Ground

There is no connection between the analog signal paths and GND. The analog signal paths consist of an N-channel and P-channel MOSFET with their sources and drains paralleled and their gates driven out of phase to V+ and V- by the logic-level translators.

V+ and GND power the internal logic and logic-level translators and set the input logic thresholds. The logic-level translators convert the logic levels to switched V+ and V- signals to drive the gates of the switches. This

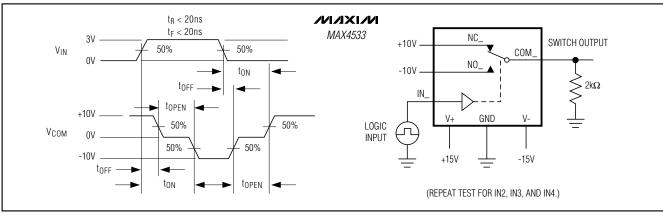
drive signal is the only connection between the power supplies and the analog signals. GND, IN_, and COM_ have ESD protection diodes to V+ and V-.

Supply Current Reduction

When the logic signals are driven rail-to-rail from 0 to +12V or -15V to +15V, the supply current reduces to approximately half of the supply current when the logic input levels are at 0 to 5V.

Power Supplies

The MAX4533 operates with bipolar supplies between $\pm 4.5V$ and $\pm 18V$. The V+ and V- supplies need not be symmetrical, but their difference can not exceed the absolute maximum rating of +44V. The MAX4533 operates from a single supply between +9V and +36V when V- is connected to GND.



Test Circuits/Timing Diagrams

Figure 2. Switching-Time Test Circuit

10

Test Circuits/Timing Diagrams (continued)

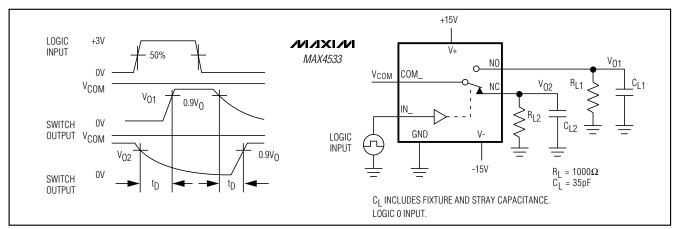
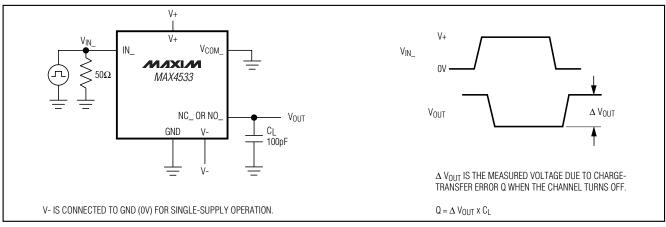
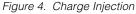
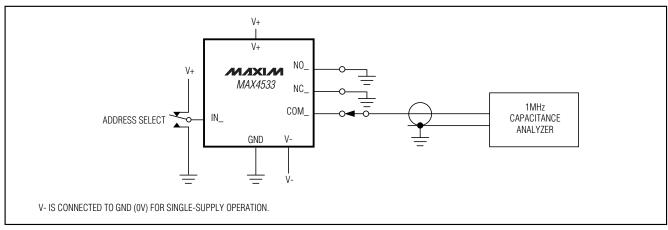


Figure 3. Break-Before-Make











MAX4533

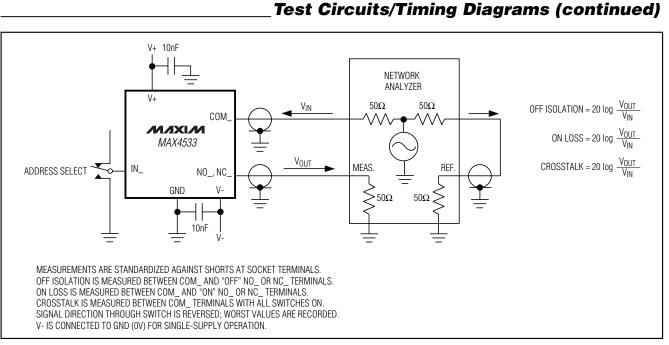


Figure 6. Frequency Response, Off-Isolation, and Crosstalk

Ordering Information (continued)

DADT	TEMP DANOE	
PART	TEMP. RANGE	PIN-PACKAGE
MAX4533CPP	0°C to +70°C	20 Plastic DIP
MAX4533EAP	-40°C to +85°C	20 SSOP
MAX4533EWP	-40°C to +85°C	20 Wide SO
MAX4533EPP	-40°C to +85°C	20 Plastic DIP
MAX4533MJP	-55°C to +125°C	20 CERDIP

Chip Information

TRANSISTOR COUNT: 448

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

12

____Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

© 1999 Maxim Integrated Products

Printed USA *Maxim* is a registered trademark of Maxim Integrated Products.